

Description

Features

- Advanced Trench Technology
- Excellent $R_{DS(ON)}$ and Low Gate Charge
- Lead free product is acquired

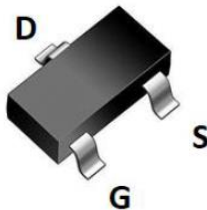
Application

- Load Switch
- PWM Application
- Power management

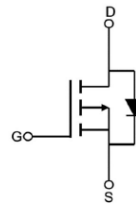
V_{DS}	30	V
$R_{ds(on),typ}@V_{gs}=10V$	18	mΩ
$R_{ds(on),typ}@V_{gs}=4.5V$	28	mΩ
I_D	5.8	A



Top View



Pin Configuration



Package Marking and Ordering Information

Part	Marking	Package	Packing	Reel Size	Tape Width	Qty
CMT3404R	3404	SOT-23	Reel	NA	NA	5000pcs

Key Performance Parameters

Symbol	Parameter	Rating	Units
V_{DS}	Drain-Source Voltage	30	V
V_{GS}	Gate-Source Voltage	± 20	V
$I_D@T_c=25^\circ C$	Continuous Drain Current, $V_{GS}=10V$	5.8	A
$I_D@T_c=100^\circ C$	Continuous Drain Current, $V_{GS}=10V$	4.3	A
IDM	Pulsed Drain Current ¹	23.2	A
$PD@T_c=25^\circ C$	Total Power Dissipation	1.47	W
T_{STG}	Storage Temperature Range	-55 to 150	$^\circ C$
T_j	Operating Junction Temperature Range	-55 to 150	$^\circ C$

Thermal Data

Symbol	Parameter	Typ	Max	Units
$R_{\theta JC}$	Thermal Resistance Junction-Case	69	85	°C/W

Electrical Characteristics ($T_J=25\text{ }^{\circ}\text{C}$, Unless otherwise noted)

Symbol	Parameter	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
BVDSS	Drain-Source Breakdown Voltage	30	--	--	V	$V_{GS}=0V$, $I_D=250\mu A$
$R_{DS(ON)}$	Static Drain-Source On-Resistance	--	18	25	$m\Omega$	$V_{GS}=10V$, $I_D=5.5A$
		--	28	40		$V_{GS}=4.5V$, $I_D=4.5A$
$V_{GS(th)}$	Gate Threshold Voltage	1.0	1.5	2.5	V	$V_{GS}=V_{DS}$, $I_D=250\mu A$
IDSS	Drain-Source Leakage Current	--	--	1	μA	$V_{DS}=30V$, $V_{GS}=0V$, $T_J=25^{\circ}\text{C}$
		--	--	10	μA	$V_{DS}=24V$, $V_{GS}=0V$, $T_J=125^{\circ}\text{C}$
IGSS	Gate-Source Leakage Current	--	--	± 100	nA	$V_{GS}=\pm 20V$, $V_{DS}=0V$
g_{fs}	Forward Transconductance	--	21	--	S	$V_{DS}=5V$, $I_D=5.5A$
R_g	Gate Resistance	--	2.1	--	Ω	$V_{DS}=0V$, $V_{GS}=0V$, $f=1\text{MHz}$
Qg	Total Gate Charge	--	5.3	--	nC	$V_{DS}=15V$, $V_{GS}=10V$, $I_D=5.8A$
Qgs	Gate-Source Charge	--	1	--		
Qgd	Gate-Drain Charge	--	1.4	--		
$T_{d(on)}$	Turn-On Delay Time	--	4.6	--	ns	$V_{DD}=15V$, $V_{GS}=10V$, $R_G=3\Omega$ $I_D=3A$
T_r	Rise Time	--	2.5	--		
$T_{d(off)}$	Turn-Off Delay Time	--	14.6	--		
T_f	Fall Time	--	3.6	--		
Ciss	Input Capacitance	--	494	--	pF	$V_{DS}=15V$, $V_{GS}=0V$, $f=1\text{MHz}$
Coss	Output Capacitance	--	118	--		
Crss	Reverse Transfer Capacitance	--	69	--		

Diode Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Units
I_S	Continuous Source Current	$V_G=V_D=0V$, Force Current	--	--	5.8	A
I_{sm}	Pulsed Source Current		--	--	23.2	A
V_{SD}	Diode Forward Voltage	$V_{GS}=0V$, $I_S=2A$, $T_J=25^{\circ}\text{C}$	--	--	1.2	V

Note:

1. Repetitive Rating: Pulsed width limited by maximum junction temperature.
2. The data tested by pulsed, pulse width $\leq 300\mu s$, duty cycle $\leq 2\%$.
3. Essentially independent of operating temperature.

Typical Performance Characteristics

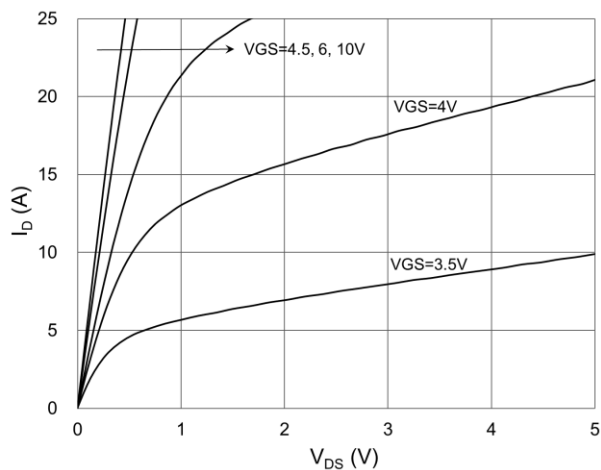
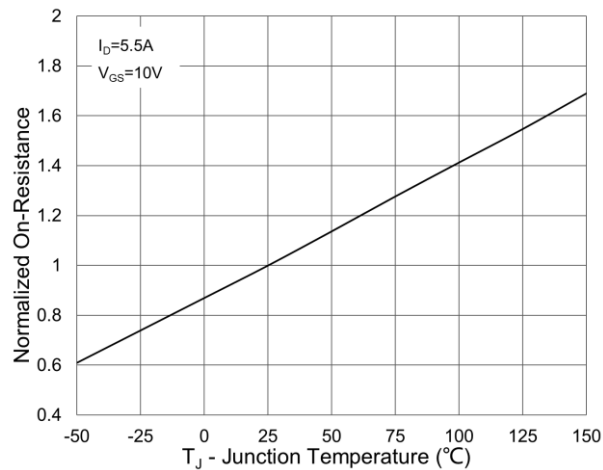
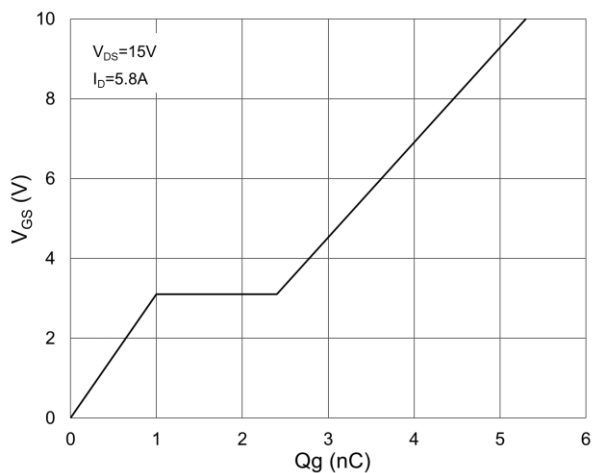
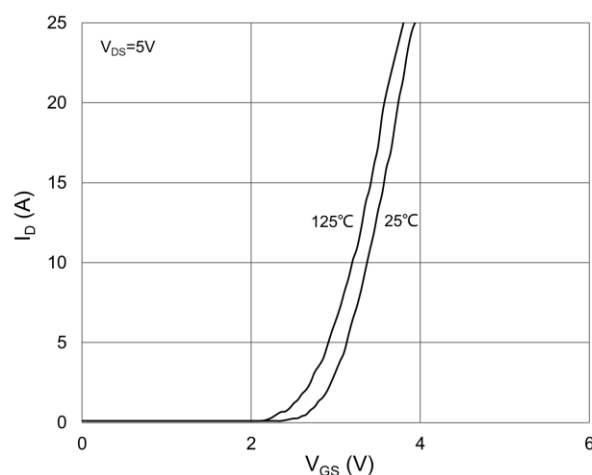
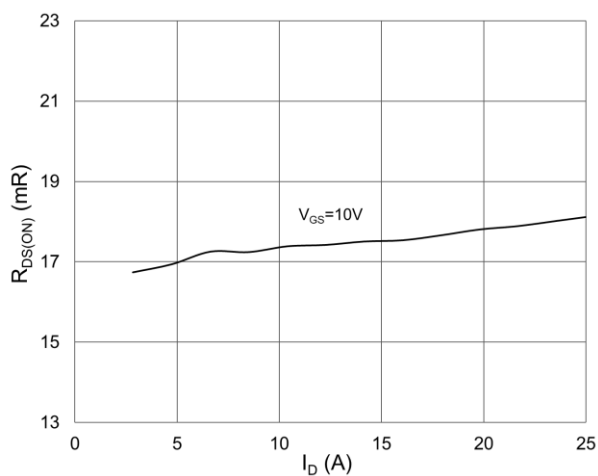
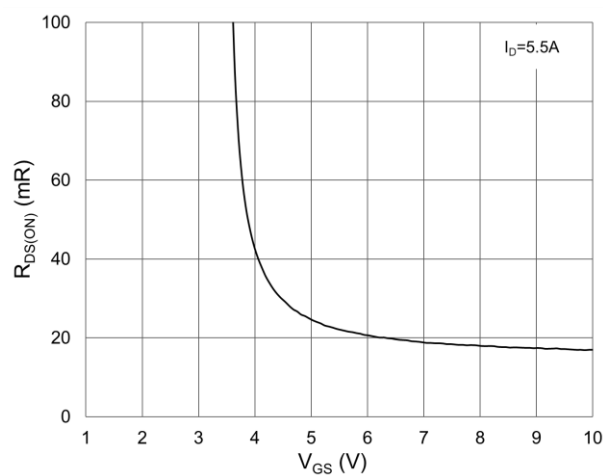
Fig1 Output Characteristics

Fig2 Normalized $R_{DS(on)}$ vs. T_J

Fig3 Gate Charge Waveform

Fig4 Transfer Characteristics

Fig5 $R_{DS(on)}$ vs. Drain Current and Gate Voltage

Fig6 $R_{DS(on)}$ vs. Gate Voltage


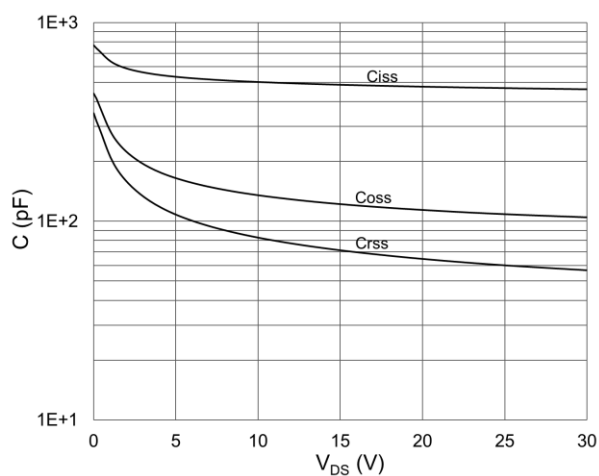
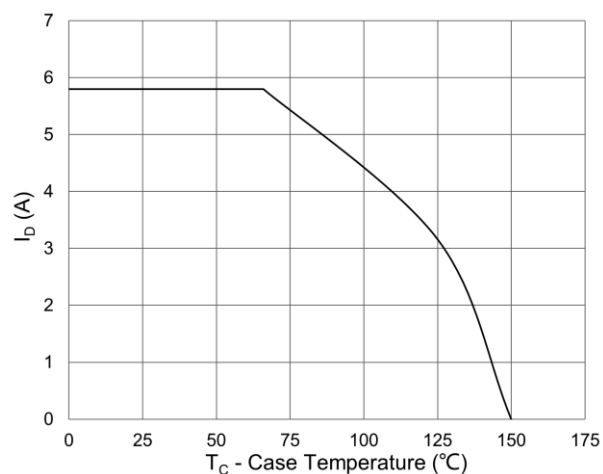
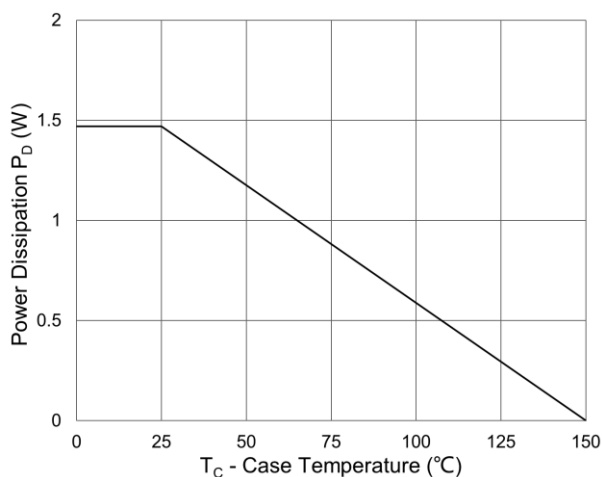
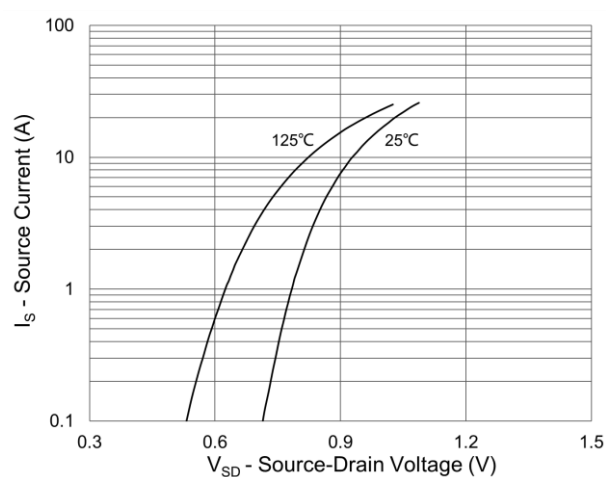
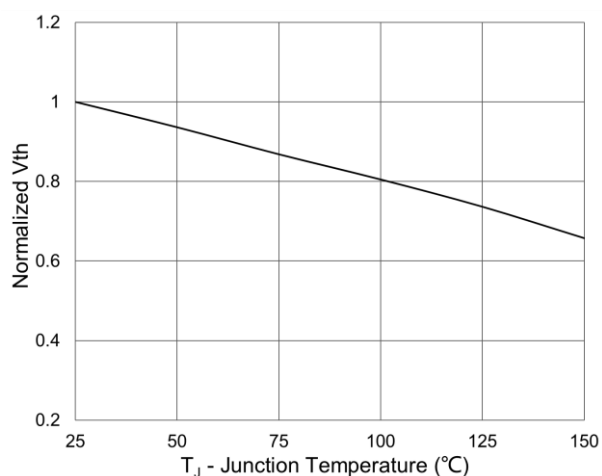
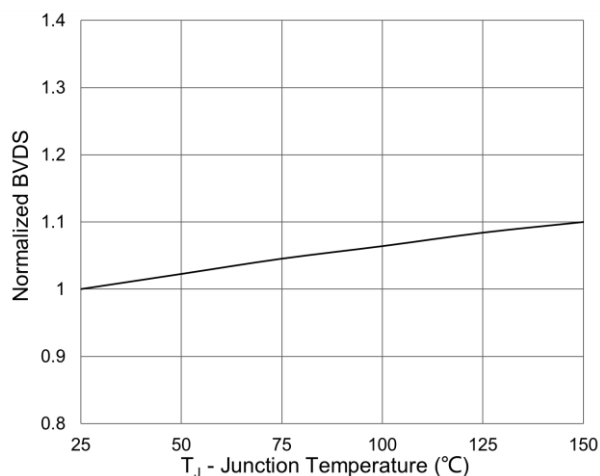
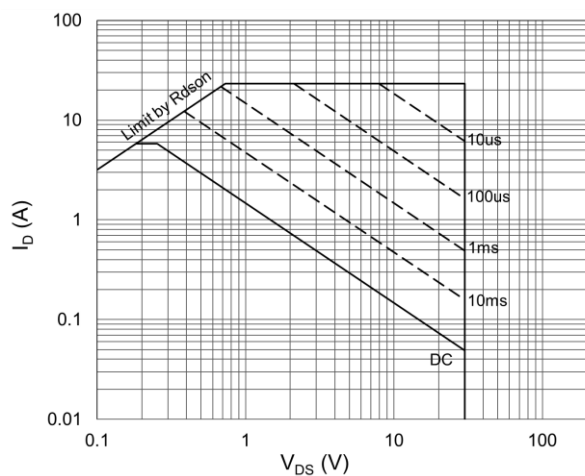
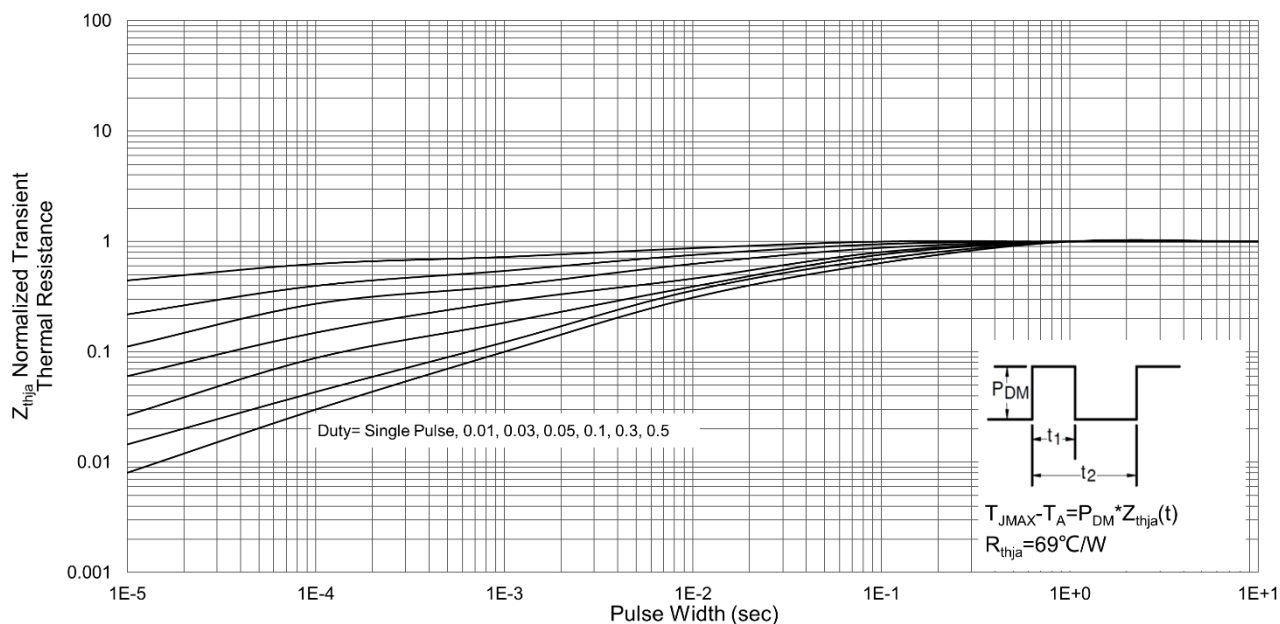
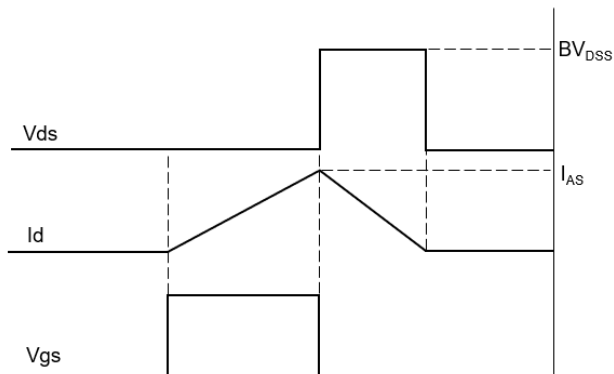
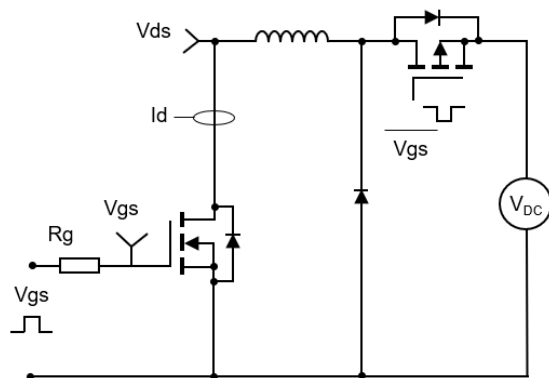
Fig7 Capacitance Characteristics

Fig8 Drain Current Derating

Fig9 Power Dissipation

Fig10 Source-Drain Diode Forward Characteristics

Fig11 Normalized Threshold Voltage vs. T_J

Fig12 Normalized Breakdown Voltage vs. T_J


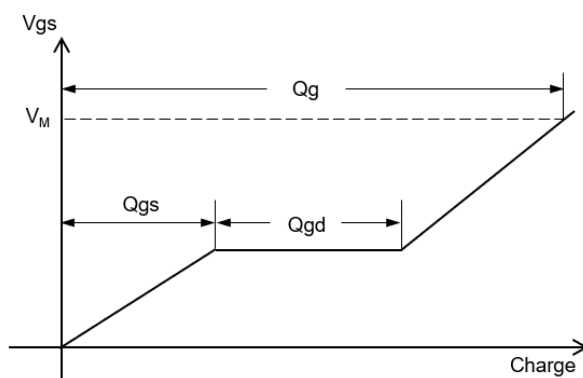
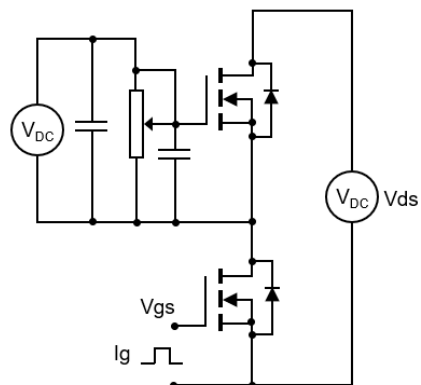
Fig13 Maximum Safe Operation Area

Fig14 Normalized Transient Impedance


Test Circuit & Waveform

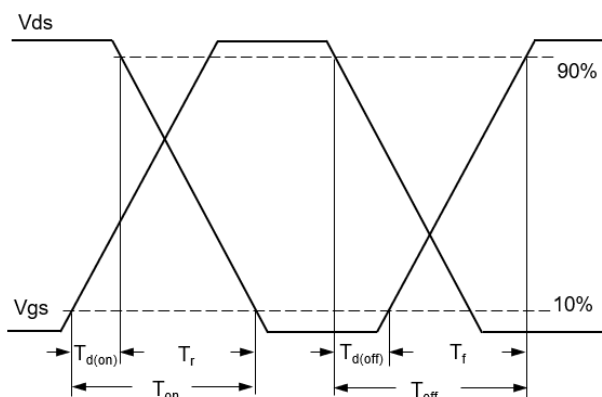
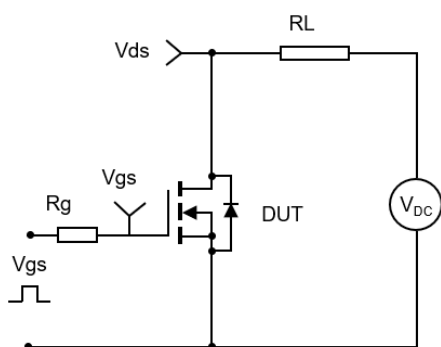
1. Unclamped Inductive Switching Test Circuit & Waveform



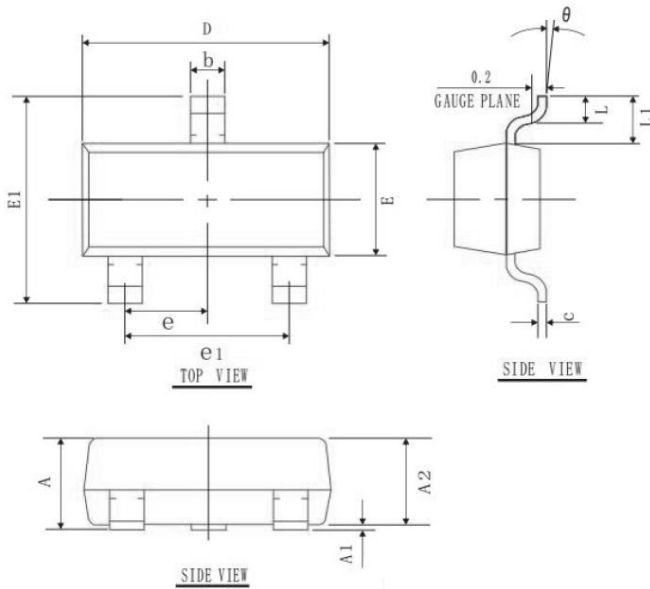
2. Gate Charge Test Circuit & Waveform



3. Resistive Switching Test Circuit & Waveform



SOT-23 Package Information



COMMON DIMENSIONS
(UNITS OF MEASURE=mm)

SYMBOL	MIN	NOM	MAX
A	0.90	1.05	1.20
A1	0.00	0.05	0.10
A2	0.90	1.00	1.10
b	0.30	0.40	0.50
c	0.08	0.10	0.15
D	2.80	2.90	3.00
E	1.20	1.30	1.40
E1	2.30	2.40	2.50
L	0.30	0.40	0.50
θ	0°	5°	10°
L1	0.55 REF		
e	0.95 BSC		
e1	1.90 REF		